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Inclosure Material:

Metal

Overall Length:

0.935 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-60

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

55.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 3.5 emitter to

base voltage, static, collector open

Current Rating Per Characteristic:

Between 400.00 milliamperes source cutoff current and 400.00 milliamperes source cutoff current

Power Rating Per Characteristic:

4.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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